

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT78 plastic package intended for use in applications requiring sensitive gate, high bidirectional blocking voltage capability and high thermal cycling performance.

2. Features and benefits

- High bidirectional blocking voltage capability
- High surge current capability
- High thermal cycling performance
- Sensitive gate

3. Applications

- Ignition circuits
- Motor control
- Protection circuits
- Voltage regulation

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	-	650	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 109 °C; <u>Fig. 1</u>	-	-	7.5	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 109 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	-	12	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>	-	-	120	A
		half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 8.3 \text{ ms}$	-	-	132	A
Tj	junction temperature		-	-	125	°C
Static chara	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	2	5	mA
Dynamic ch	naracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 436 V; T _j = 125 °C; R _{GK} = 100 Ω; (V_{DM} = 67% of V_{DRM}); exponential waveform; Fig. 12	200	1000	-	V/µs

5. Pinning information

i adle 2.	Pinning in	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	А-Ӈ-К
2	A	anode		G sym037
3	G	gate		Symoor
mb	A	mounting base; connected to anode	TO-220AB (SOT78)	

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BT151-650L	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78			



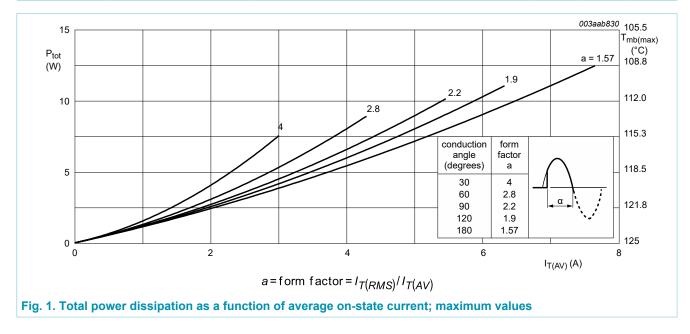
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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

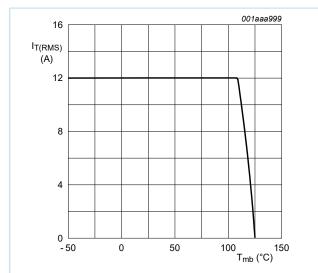
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	650	V
V _{RRM}	repetitive peak reverse voltage		-	650	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 109 °C; <u>Fig. 1</u>	-	7.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 109 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	12	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	-	120	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	132	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	72	A²s
dl _T /dt	rate of rise of on-state current	I _G = 10 mA	-	50	A/µs
I _{GM}	peak gate current		-	2	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C

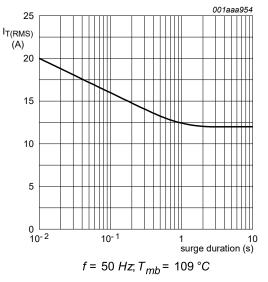


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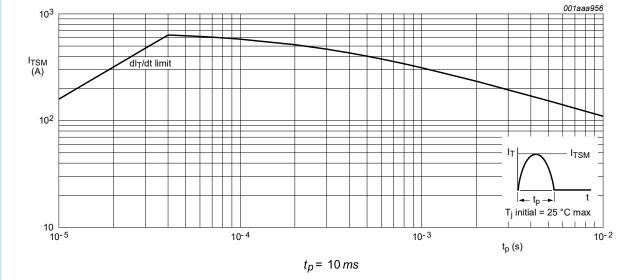
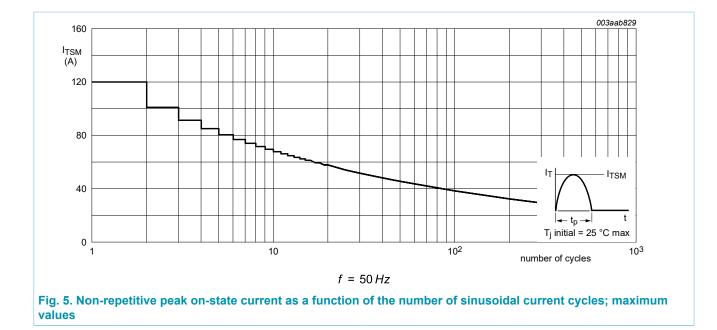


Fig. 4. Non-repetitive peak on-state current as a function of pulse width for sinusoidal currents; maximum values

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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. <u>6</u>	-	-	1.3	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

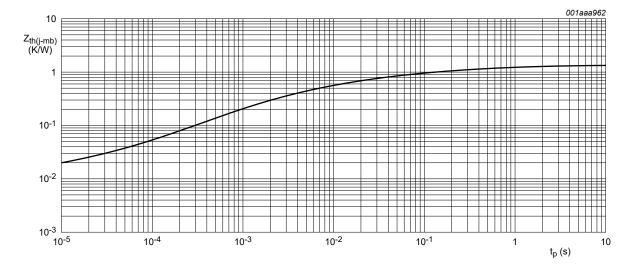


Fig. 6. Transient thermal impedance from junction to mounting base as a function of pulse width

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9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	2	5	mA
IL	latching current	V_D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	-	10	40	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	7	20	mA
V _T	on-state voltage	I _T = 23 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.75	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11	-	0.6	1	V
		V_D = 650 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11	0.25	0.4	-	V
I _D	off-state current	V _D = 650 V; T _j = 125 °C	-	0.1	0.5	mA
I _R	reverse current	V _R = 650 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic ch	aracteristics					
dV _D /dt	rate of rise of off-state voltage	$ V_{DM} = 436 \text{ V}; \text{T}_{\text{j}} = 125 ^\circ\text{C}; \text{R}_{\text{GK}} = 100 \Omega; \\ (\text{V}_{\text{DM}} = 67\% \text{ of } \text{V}_{\text{DRM}}); \text{ exponential} \\ waveform; \underline{\text{Fig. } 12} $	200	1000	-	V/µs
		V_{DM} = 436 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12	50	130	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 40 A; V _D = 650 V; I _G = 0.1 A; dI _G / dt = 5 A/µs; T _j = 25 °C	-	2	-	μs
t _q	commutated turn-off time	V_{DM} = 436 V; T _j = 125 °C; I _{TM} = 20 A; V_R = 25 V; (dI _T /dt) _M = 30 A/µs; dV _D / dt = 50 V/µs; R _{GK(ext)} = 100 Ω; (V _{DM} = 67% of V _{DRM})	-	70	-	μs

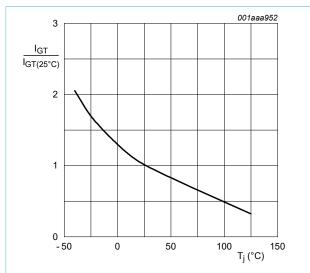


Fig. 7. Normalized gate trigger current as a function of junction temperature

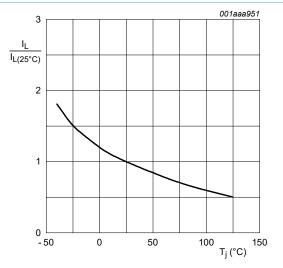
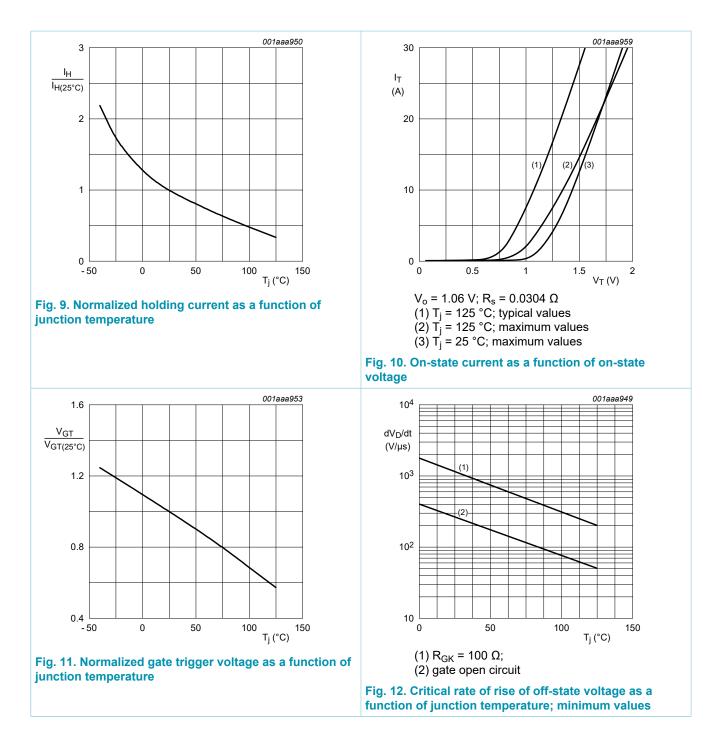


Fig. 8. Normalized latching current as a function of junction temperature

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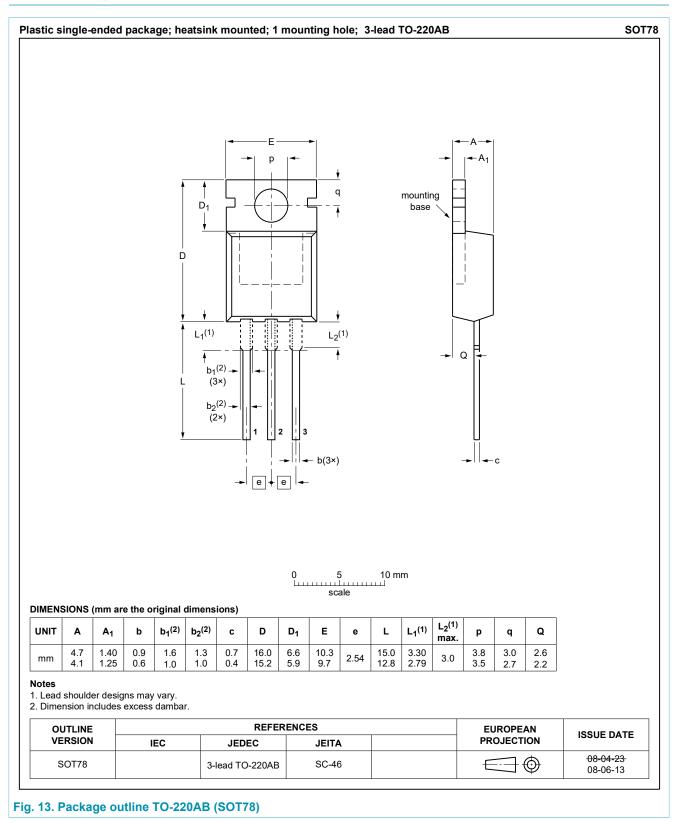
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10. Package outline



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11. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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